General Purpose Transistor

NPN Silicon

Features

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	25	Vdc
Collector-Base Voltage	V _{CBO}	30	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1) @T _A = 25°C Derate above 25°C	P _D	225 1.8	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) @T _A = 25°C Derate above 25°C	P _D	300 2.4	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

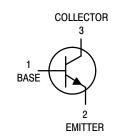
1. FR-5 = 1.0 \times 0.75 \times 0.062 in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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MARKING DIAGRAM



ZC = Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

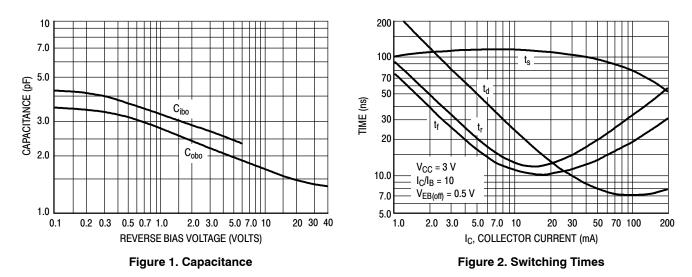
Device	Package	Shipping [†]
MMBT4124LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

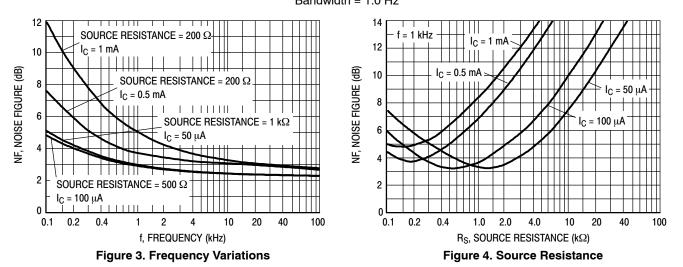
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS		•		
Collector – Emitter Breakdown Voltage (Note 3) $(I_{C} = 1.0 \text{ mAdc}, I_{E} = 0)$	V _(BR) CEO	25	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	V _(BR) CBO	30	_	Vdc
Emitter-Base Breakdown Voltage (I _E = 10 μ Adc, I _C = 0)	V _{(BR)EBO}	5.0	_	Vdc
Collector Cutoff Current ($V_{CB} = 20 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	50	nAdc
Emitter Cutoff Current ($V_{EB} = 3.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	50	nAdc
ON CHARACTERISTICS		1		
DC Current Gain (Note 3) (I _C = 2.0 mAdc, V _{CE} = 1.0 Vdc) (I _C = 50 mAdc, V _{CE} = 1.0 Vdc)	h _{FE}	120 60	360 -	-
Collector – Emitter Saturation Voltage (Note 3) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)	V _{CE(sat)}	-	0.3	Vdc
Base – Emitter Saturation Voltage (Note 3) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)	V _{BE(sat)}	-	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	I	1		
Current–Gain – Bandwidth Product (I _C = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)	f _T	300	-	MHz
Input Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	C _{ibo}	-	8.0	pF
Collector–Base Capacitance ($I_E = 0$, $V_{CB} = 5.0$ V, f = 1.0 MHz)	C _{cb}	-	4.0	pF
Small–Signal Current Gain (I _C = 2.0 mAdc, V _{CE} = 10 Vdc, R _S = 10 k Ω, f = 1.0 kHz)	h _{fe}	120	480	-
Current Gain – High Frequency ($I_C = 10 \text{ mAdc}$, $V_{CE} = 20 \text{ Vdc}$, f = 100 MHz) ($I_C = 2.0 \text{ mAdc}$, $V_{CE} = 10 \text{ V}$, f = 1.0 kHz)	h _{fe}	3.0 120	_ 480	_
Noise Figure (I _C = 100 μAdc, V _{CE} = 5.0 Vdc, R _S = 1.0 k Ω, f = 1.0 kHz)	NF	-	5.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle = 2.0%.

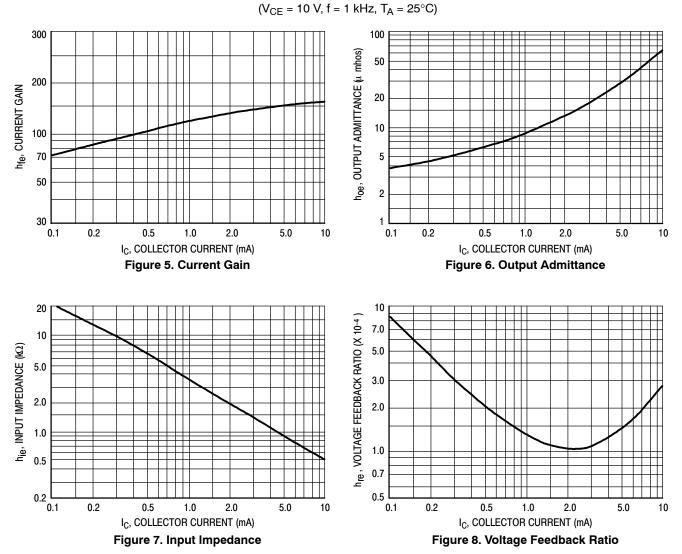




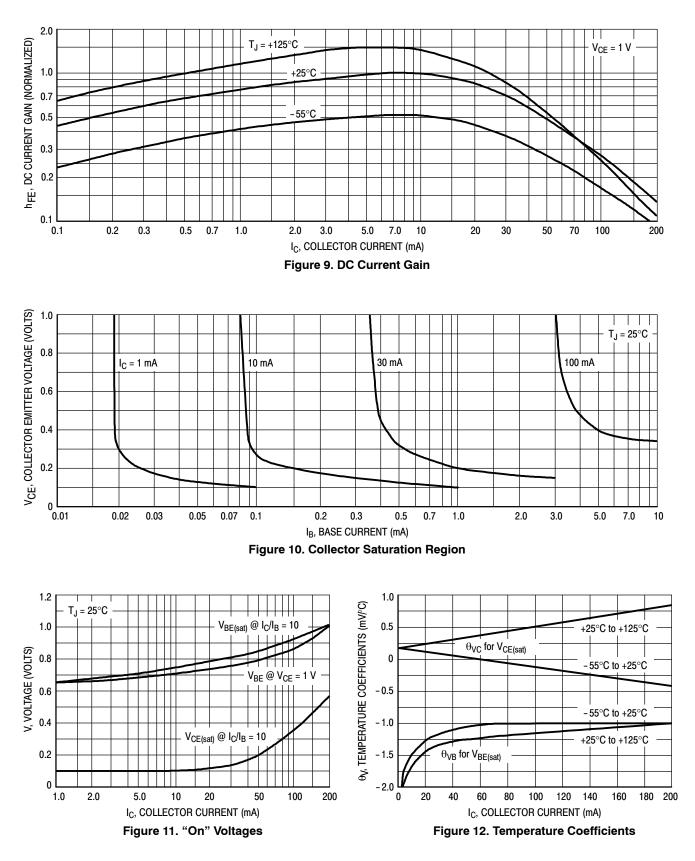
 $\begin{array}{l} (V_{CE}=5 \; Vdc, \; T_{A}=25^{\circ}C) \\ Bandwidth=1.0 \; Hz \end{array}$



h PARAMETERS



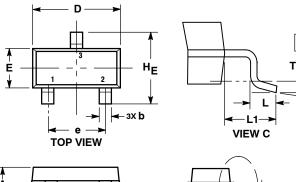
STATIC CHARACTERISTICS

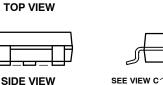


PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR**

0.25





END VIEW

NOTES:

1. 2.

DES.: DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF з.

THE BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4

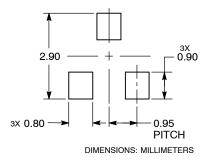
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
ΗE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0 °		10 °

STYLE 6: BASE PIN 1.

2 FMITTER

COLLECTOR 3

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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